
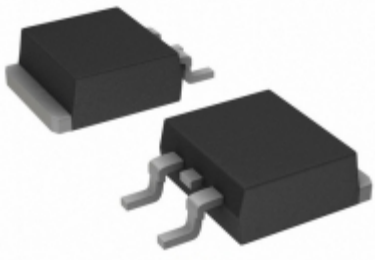






	<h2 style="color: red;">FQB9P25TM</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQB9P25TM</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 250V 9.4A D2PAK</p> <p><b>Datenblätter:</b>  <a href="#">FQB9P25TM.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 1706 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	FQB9P25TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 250V 9.4A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	1706 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 120W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9.4A (Tc)
Rds On (Max) @ Id, Vgs	620 mOhm @ 4.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1180pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB9P25TM ist neu im Original, Suche FQB9P25TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB9P25TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB9P25TM: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQB9P25</b> FSC FSC TO-263</p>	 <p><b>FQB9P25TM-NL</b> FSC FSC TO-263</p>	 <p><b>FQB9P25TM</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 250V 9.4A D2PAK</p>	 <p><b>FQB9N50CFTM</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>
 <p><b>FQB9N50TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p><b>FQB9N50CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p><b>FQB9N50CFTM_WS</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>	 <p><b>FQB9N50TM</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 9A D2PAK</p>

### heiße Teile

Mehr

 FQB6N70TM	 FQB6N90TM	 FQB6N90TM_AM002	 FQB6N90TM_AM002	 FQB7042FB
 FQB7045FB	 FQB70N03	 FQB70N06	 FQB70N08	 FQB70N10TM
 FQB7N10L	 FQB7N20L	 FQB7N60TM	 FQB7N60TM	 FQB7N65C
 FQB7N65CTM	 FQB7N65CTM	 FQB7P20TM	 FQB7P20TM	 FQB85N06
 FQB85N06TM	 FQB8N25TM	 FQB8N25TM	 FQB8N60C	 FQB8N60CFTM
 FQB8N60CFTM	 FQB8N60CTM	 FQB8N60CTM	 FQB8N60TM	 FQB8N90CTM
 FQB8N90CTM	 FQB8P10TM	 FQB8P10TM	 FQB8P10TM-NL	 FQB9N08L
 FQB9N08LTM	 FQB9N08LTM	 FQB9N25C	 FQB9N25CTM	 FQB9N25CTM
 FQB9N25TM	 FQB9N25TM	 FQB9N50C	 FQB9N50CFTM	 FQB9N50CFTM
 FQB9N50CTM	 FQB9N50CTM	 FQB9N50TM	 FQB9N50TM	 FQB9P25TM

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